CDCV857B, CDCV857BI 2.5-V PHASE-LOCK LOOP CLOCK DRIVER

SCAS689A - FEBRUARY 2003 - REVISED NOVEMBER 2010

- **Phase-Lock Loop Clock Driver for Double Data-Rate Synchronous DRAM Applications**
- **Spread Spectrum Clock Compatible**
- Operating Frequency: 60 MHz to 200 MHz
- Low Jitter (cycle-cycle): ±50 ps Low Static Phase Offset: ±50 ps
- Low Jitter (Period): ±35 ps
- **Distributes One Differential Clock Input to** 10 Differential Outputs

- **Enters Low-Power Mode When No CLK** Input Signal Is Applied or PWRDWN Is Low
- **Operates From Dual 2.5-V Supplies**
- Available in a 48-Pin TSSOP Package or 56-Ball MicroStar Junior™ BGA Package
- Consumes < 100-µA Quiescent Current
- External Feedback Pins (FBIN, FBIN) Are Used to Synchronize the Outputs to the **Input Clocks**
- Meets/Exceeds the Latest DDR JEDEC Spec JESD82-1

Description

The CDCV857B is a high-performance, low-skew, low-jitter zero delay buffer that distributes a differential clock input pair (CLK, $\overline{\text{CLK}}$) to 10 differential pairs of clock outputs (Y[0:9], $\overline{\text{Y[0:9]}}$) and one differential pair of feedback clock outputs (FBOUT, FBOUT). The clock outputs are controlled by the clock inputs (CLK, CLK), the feedback clocks (FBIN, $\overline{\text{FBIN}}$), and the analog power input (AV_{DD}). When $\overline{\text{PWRDWN}}$ is high, theoutputs switch in phase and frequency with CLK. When PWRDWN is low, all outputs are disabled to a high-impedance state (3-state) and the PLL is shut down (low-power mode). The device also enters this low-power mode when the input frequency falls below a suggested detection frequency that is below 20 MHz (typical 10 MHz). An input frequency detection circuit detects the low frequency condition and, after applying a >20-MHz input signal, this detection circuit turns the PLL on and enables the outputs.

When AV_{DD} is strapped low, the PLL is turned off and bypassed for test purposes. The CDCV857B is also able to track spread spectrum clocking for reduced EMI.

Since the CDCV857B is based on PLL circuitry, it requires a stabilization time to achieve phase-lock of the PLL. This stabilization time is required following power up. The CDCV857B is characterized for both commercial and industrial temperature ranges.

AVAILABLE OPTIONS

T _A	TSSOP (DGG)	MicroStar Junior™ BGA (GQL)
0°C to 85°C	CDCV857BDGG	CDCV857BGQL
-40°C to 85°C	CDCV857BIDGG	_

FUNCTION TABLE (Select Functions)

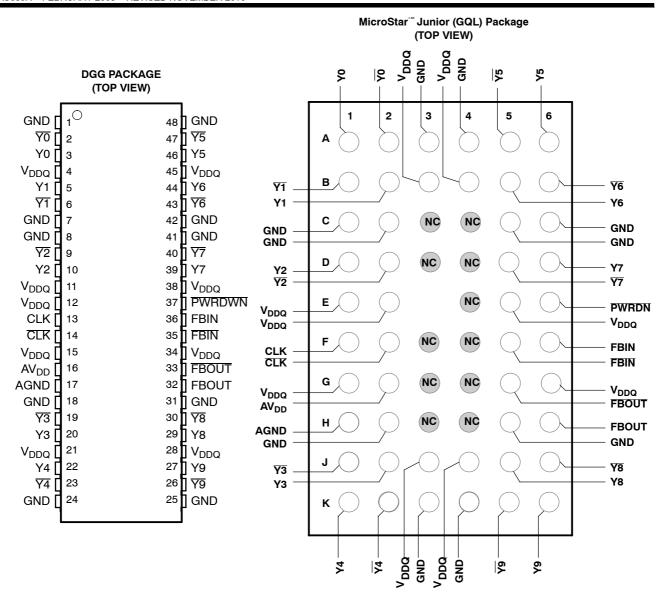
	INPUTS	3			OU.		PLL	
AV _{DD}	PWRDWN	CLK	CLK	Y[0:9]	Y[0:9]	FBOUT	FBOUT	
GND	Н	L	Н	L	Н	L	Н	Bypassed/Off
GND	Н	Н	L	Н	L	Н	L	Bypassed/Off
Х	L	L	Н	Z	Z	Z	Z	Off
Х	L	Н	L	Z	Z	Z	Z	Off
2.5 V (nom)	Н	L	Н	L	Н	L	Н	On
2.5 V (nom)	Н	Н	L	Н	L	Н	L	On
2.5 V (nom)	Х	<20 MHz	<20 MHz	Z	Z	Z	Z	Off



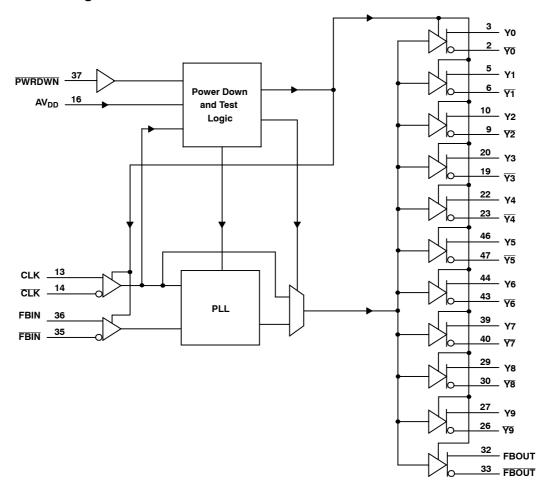
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functional block diagram



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Terminal Functions

Т	ERMINAL			DECODINE ON
NAME	DGG	GQL		DESCRIPTION
AGND	17	H1		Ground for 2.5-V analog supply
AV_{DD}	16	G2		2.5-V Analog supply
CLK, CLK	13, 14	F1, F2	1	Differential clock input
FBIN, FBIN	35, 36	F5, F6	I	Feedback differential clock input
FBOUT, FBOUT	32, 33	H6, G5	0	Feedback differential clock output
GND	1, 7, 8, 18, 24, 25, 31, 41, 42, 48	A3, A4, C1, C2, C5, C6, H2, H5, K3, K4		Ground
PWRDWN	37	E6	I	Output enable for Y and \overline{Y}
V _{DDQ}	4, 11, 12, 15, 21, 28, 34, 38, 45	B3, B4, E1, E2, E5, G1, G6, J3, J4		2.5-V Supply
Y[0:9]	3, 5, 10, 20, 22, 27, 29, 39, 44, 46	A1, B2, D1, J2, K1, A6, B5, D6, J5, K6	0	Buffered output copies of input clock, CLK
Y[0:9]	2, 6, 9, 19, 23, 26, 30, 40, 43, 47	A2, B1, D2, J1, K2, A5, B6, D5, J6, K5	0	Buffered output copies of input clock, CLK

absolute maximum ratings over operating free-air temperature (unless otherwise noted)[†]

Supply voltage range, V _{DDQ} , AV _{DD}	0.5 V to 3.6 V
Input voltage range, V _I (see Notes 1 and 2)	\dots -0.5 V to V_{DDQ} + 0.5 V
Output voltage range, V _O (see Notes 1 and 2)	\dots -0.5 V to V_{DDQ} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{DDQ}$)	±50 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{DDQ})	±50 mA
Continuous output current, I _O (V _O = 0 to V _{DDQ})	±50 mA
Continuous current to GND or V _{DDQ}	±100 mA
Package thermal impedance, θ _{JA} (see Note 3): GQL package	137.6°C/W
Storage temperature range T _{stg}	–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

- 2. This value is limited to 3.6 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.



recommended operating conditions (see Note 4)

			MIN	TYP MAX	UNIT
0 1 1		V_{DDQ}	2.3	2.7	V
Supply voltage		AV _{DD}	V _{DDQ} – 0.12	2.7	V
Low-level input voltage, V _{IL}		, CLK, FBIN, FBIN		V _{DDQ} /2 – 0.18	.,
		RDWN	-0.3	0.7	٧
High-level input voltage, V_{IH}		, CLK, FBIN, FBIN	V _{DDQ} /2 + 0.18		.,
		RDWN	1.7	V _{DDQ} + 0.3	V
DC input signal voltage (see Note 5)			-0.3	V _{DDQ} + 0.3	V
Differential in the second allows V (see Nate C)	dc	CLK, FBIN	0.36	V _{DDQ} + 0.6	.,
Differential input signal voltage, V _{ID} (see Note 6)	ac	CLK, FBIN	0.7	V _{DDQ} + 0.6	V
Input differential pair cross voltage, V_{IX} (see Note 7)		V _{DDQ} /2 – 0.2	V _{DDQ} /2 + 0.2	V
High-level output current, I _{OH}				-12	mA
Low-level output current, I _{OL}				12	mA
Input slew rate, SR	1	4	V/ns		
Occupies for sixteness of the T		Commercial	0	85	
Operating free-air temperature, T _A		Industrial	-40	85	°C

NOTES: 4. The unused inputs must be held high or low to prevent them from floating.

- 5. The dc input signal voltage specifies the allowable dc execution of the differential input.
- 6. The differential input signal voltage specifies the differential voltage |VTR VCP| required for switching, where VTR is the true input level and VCP is the complementary input level.
- 7. The differential cross-point voltage is expected to track variations of V_{CC} and is the voltage at which the differential signals must be crossing.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
V _{IK}	Input voltage	All inputs	$V_{\rm DDQ} = 2.3 \text{ V}, I_{\rm I} = -18 \text{ mA}$			-1.2	V
V	District of the first of the second		$V_{\rm DDQ}$ = min to max, $I_{\rm OH}$ = -1 mA	V _{DDQ} - 0.1			.,
V _{OH}	OH High-level output voltage		$V_{DDQ} = 2.3 \text{ V}, I_{OH} = -12 \text{ mA}$	1.7			V
.,	V _{OL} Low-level output voltage				0.1	\ \	
VOL			$V_{DDQ} = 2.3 \text{ V}, I_{OL} = 12 \text{ mA}$			0.6	V
V_{OD}	Output voltage swing [‡]		Differential outputs are terminated	1.1		$V_{DDQ} - 0.4$	
V _{OX}	Output differential cross-vo	oltage [§]	with 120 Ω /CL = 14 pF (See Figure 3)	V _{DDQ} /2 - 0.15	V _{DDQ} /2	V _{DDQ} /2 + 0.15	V
I	Input current		$V_{DDQ} = 2.7 \text{ V}, V_{I} = 0 \text{ V to } 2.7 \text{ V}$			±10	μΑ
l _{OZ}	High-impedance state outp	out current	$V_{\rm DDQ}$ = 2.7 V, $V_{\rm O}$ = $V_{\rm DDQ}$ or GND			±10	μΑ
I _{DDPD}	Power-down current on V _{DDQ} + AV _{DD}		CLK and $\overline{\text{CLK}}$ = 0 MHz; $\overline{\text{PWRDWN}}$ = Low; Σ of I _{DD} and AI _{DD}		20	100	μА
	Overally assessed an AV		f _O = 170 MHz		7	10	A
Al _{DD}	Supply current on AV _{DD}		f _O = 200 MHz		9	12	mA
CI	Input capacitance		$V_{DDQ} = 2.5 \text{ V}, V_I = V_{DDQ} \text{ or GND}$	2	2.5	3.5	pF

 $^{^{\}dagger}$ All typical values are at a respective nominal $V_{\mbox{\scriptsize DDQ}}.$



[‡] The differential output signal voltage specifies the differential voltage |VTR - VCP|, where VTR is the true output level and VCP is the complementary output level.

[§] The differential cross-point voltage is expected to track variations of V_{DDQ} and is the voltage at which the differential signals must be crossing. The frequency range is 100 MHz to 200 MHz.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted) (continued)

	PARAMETER	TEST COND	OITIONS	MIN	TYP [†]	MAX	UNIT
		Mellon I lond	f _O = 170 MHz		100	110	
		Without load	f _O = 200 MHz		105	120	
		Differential outputs	, ,	240			
I_{DD}	Dynamic current on V _{DDQ}	terminated with 120 Ω /CL = 0 pF	f _O = 200 MHz		210	250	mA
		Differential outputs	f _O = 170 MHz		260	300	
		terminated with 120 Ω /CL = 14 pF	f _O = 200 MHz		280	320	
ΔC	Part-to-part input capacitance variation	$V_{DDQ} = 2.5 \text{ V}, V_I = V_I$	DDQ or GND			1	pF
$C_{I(\Delta)}$	Input capacitance difference between CLK and CLKB, FBIN, and FBINB	$V_{DDQ} = 2.5 \text{ V}, V_I = V_{DDQ} \text{ or GND}$				0.25	pF
Co	Output capacitance	$V_{DDQ} = 2.5 \text{ V}, V_{O} =$	V _{DDQ} or GND	2.5	3	3.5	pF

[†] All typical values are at a respective nominal V_{DDQ}.

timing requirements over recommended ranges of supply voltage and operating free-air temperature

		MIN	MAX	UNIT
_	Operating clock frequency		000	MI I-
f _{CLK}	Application clock frequency	60	200	MHz
	Input clock duty cycle	40%	60%	
	Stabilization time [†] (PLL mode)		10	μs
	Stabilization time [‡] (Bypass mode)		30	ns

[†] The time required for the integrated PLL circuit to obtain phase lock of its feedback signal to its reference signal. For phase lock to be obtained, a fixed-frequency, fixed-phase reference signal must be present at CLK and V_{DD} must be applied. Until phase lock is obtained, the specifications for propagation delay, skew, and jitter parameters given in the switching characteristics table are not applicable. This parameter does not apply for input modulation under SSC application.

switching characteristics

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH} §	Low to high level propagation delay time	Test mode/CLK to any output		3.5		ns
t _{PHL} §	High-to low level propagation delay time	Test mode/CLK to any output		3.5		ns
. ¶	Place (as in the Oran Fig. 1977)	66 MHz	-60		60	ps
t _{jit(per)} ¶	Jitter (period), See Figure 7	100/133/167/200 MHz	-35		35	ps
t _{jit(cc)} ¶	Eller (a ala la a ala) Ora Fin da A	66 MHz	-75		75	
	Jitter (cycle-to-cycle), See Figure 4	100/133/167/200 MHz	-50		50	ps
. •	Half and all the Con Fig. 10	66 MHz	-100		100	
t _{jit(hper)} 1	Half-period jitter, See Figure 8	100/133/167/200 MHz	-75		75	ps
t _{slr(o)}	Output clock slew rate, See Figure 9	Load: 120 Ω/14 pF	1		2	V/ns
	0	66 MHz	-100	-100		
$t_{(\emptyset)}$	Static phase offset, See Figure 5	100/133/167/200 MHz	50	ps		
tsk _(o)	Output skew, See Figure 6	Load: 120 Ω/14 pF		70	100	ps
t _r , t _f	Output rise and fall times (20% - 80%)	Load: 120 Ω/14 pF	600		900	ps

[§] Refers to the transition of the noninverting output.

[¶] This parameter is assured by design but can not be 100% production tested.



[‡] A recovery time is required when the device goes from power-down mode into bypass mode (AVDD at GND).

PARAMETER MEASUREMENT INFORMATION

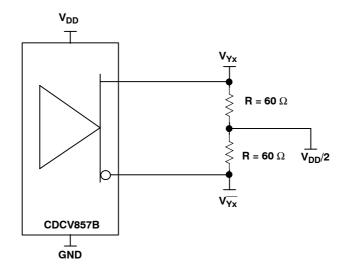


Figure 1. IBIS Model Output Load

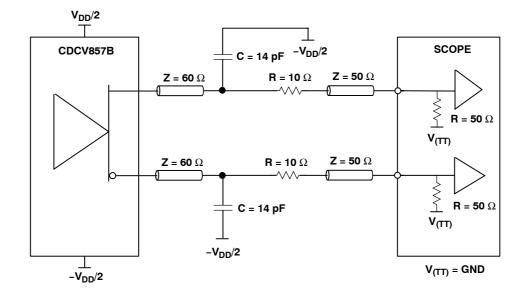


Figure 2. Output Load Test Circuit

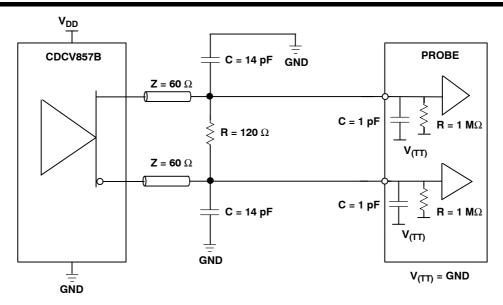


Figure 3. Output Load Test Circuit for Crossing Point

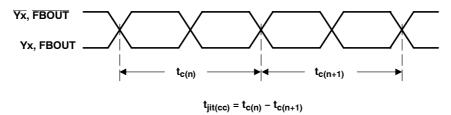


Figure 4. Cycle-to-Cycle Jitter

PARAMETER MEASUREMENT INFORMATION

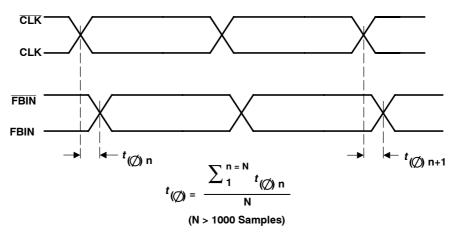


Figure 5. Phase Offset

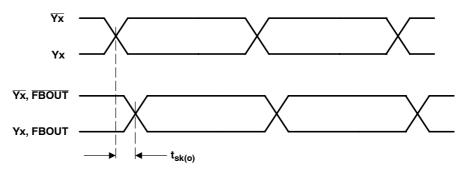


Figure 6. Output Skew

PARAMETER MEASUREMENT INFORMATION

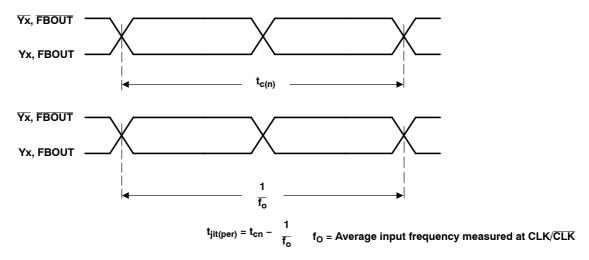


Figure 7. Period Jitter

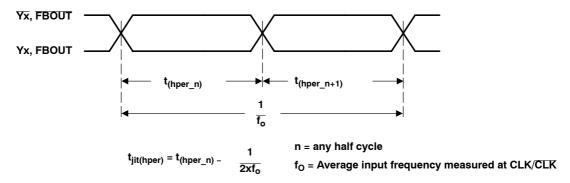


Figure 8. Half-Period Jitter

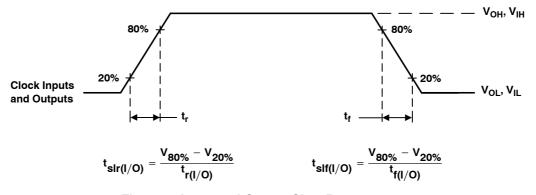


Figure 9. Input and Output Slew Rates





24-Jan-2013

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
CDCV857BDGG	ACTIVE	TSSOP	DGG	48	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	CDCV857B	Samples
CDCV857BDGGG4	ACTIVE	TSSOP	DGG	48	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	CDCV857B	Samples
CDCV857BDGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	CDCV857B	Samples
CDCV857BDGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	0 to 70	CDCV857B	Samples
CDCV857BGQLR	ACTIVE	BGA MICROSTAR JUNIOR	GQL	56	1000	TBD	SNPB	Level-2A-220C-4 WKS	0 to 70	CDCV857B	Samples
CDCV857BIDGG	ACTIVE	TSSOP	DGG	48	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CDCV857B-I	Samples
CDCV857BIDGGG4	ACTIVE	TSSOP	DGG	48	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CDCV857B-I	Samples
CDCV857BIDGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CDCV857B-I	Samples
CDCV857BIDGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	CDCV857B-I	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

24-Jan-2013

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

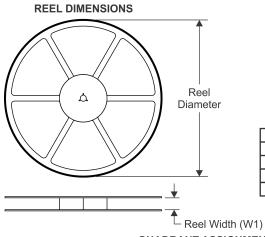
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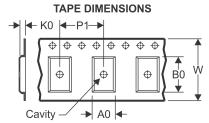
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PACKAGE MATERIALS INFORMATION

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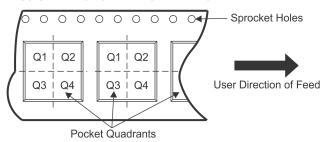
TAPE AND REEL INFORMATION





A0	
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDCV857BIDGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1

PACKAGE MATERIALS INFORMATION

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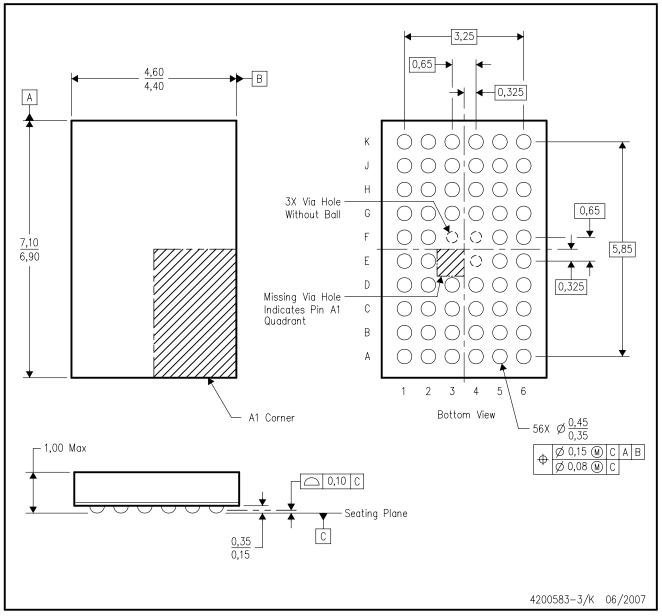


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CDCV857BIDGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0

GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

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